





# 2N6453-4

## 2N6453, 2N6454 N-Channel JFET

Support

#### **Features**

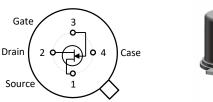
- InterFET N0132L Geometry
- Low Noise: 1.0 nV/VHz Typical
- High Gain: 20mS Minimum
- RoHS Compliant
- SMT, TH, and Bare Die Package options.

#### **Applications**

- Audio Amplifiers
- · Low-Noise, High Gain Amplifiers
- Low-Noise Preamplifiers

#### Description

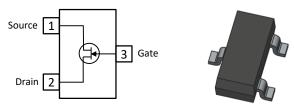
The -25V InterFET 2N6453 and 2N6454 are targeted for sensitive amplifier stages for midfrequencies designs. Gate leakages are typically less than 50pA at room temperatures. The TO-72 package is hermetically sealed and suitable for military applications.



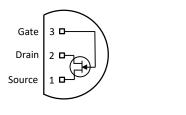




**TO-72 Bottom View** 



**TO-92 Bottom View** 





#### **Product Summary**

	Parameters	2N6453 Min	2N6454 Min	Unit
BV <sub>GSS</sub>	Gate to Source Breakdown Voltage	-20	-25	V
IDSS	Drain to Source Saturation Current	15	15	mA
V <sub>GS(off)</sub>	Gate to Source Cutoff Voltage	-0.75	-0.75	V
GFS	Forward Transconductance	20	20	mS

#### Ordering Information Custom Part and Binning Options Available

Part Number	Description	Case	Packaging
2N6453; 2N6454	Through-Hole	TO-72	Bulk
PN6453; PN6454	Through-Hole	TO-92	Bulk
SMP6453; SMP6454	Surface Mount	SOT23	Bulk
	7" Tape and Reel: Max 3,000 Pieces		Minimum 1,000 Pieces
SMP6453TR; SMP6454TR	13" Tape and Reel: Max 9,000 Pieces	SOT23	Tape and Reel
2N6453COT; 2N6454COT	Chip Orientated Tray (COT Waffle Pack)	СОТ	400/Waffle Pack
2N6453CFT; 2N6454CFT	Chip Face-up Tray (CFT Waffle Pack)	CFT	400/Waffle Pack



Disclaimer: It is the Buyers responsibility for designing, validating and testing the end application under all field use cases and extreme use conditions. Guaranteeing the application meets required standards, regulatory compliance, and all safety and security requirements is the responsibility of the Buyer. These resources are subject to change without notice.







## **Electrical Characteristics**

#### Maximum Ratings (@ T<sub>A</sub> = 25°C, Unless otherwise specified)

	Parameters	Value	Unit
VRGS	Reverse Gate Source and Gate Drain Voltage	-25	V
$I_{FG}$	Continuous Forward Gate Current	10	mA
PD	Continuous Device Power Dissipation	360	mW
Р	Power Derating	2.88	mW/°C
Τı	Operating Junction Temperature	-55 to 125	°C
T <sub>STG</sub>	Storage Temperature	-65 to 150	°C

#### **Static Characteristics** (@ TA = 25°C, Unless otherwise specified)

			2N6453		2N6454		
	Parameters	Conditions	Min	Max	Min	Max	Unit
V(BR)GSS	Gate to Source Breakdown Voltage	$V_{DS} = 0V$ , $I_G = -1\mu A$	-20		-25		v
		V <sub>GS</sub> = -10V, V <sub>DS</sub> = 0V, T <sub>A</sub> = 25°C		-0.1			~ ^
l. –	Gate to Source	V <sub>GS</sub> = -15V, V <sub>DS</sub> = 0V, T <sub>A</sub> = 25°C				-0.5	nA
I <sub>GSS</sub>	Reverse Current	V <sub>GS</sub> = -10V, V <sub>DS</sub> = 0V, T <sub>A</sub> = 125°C		-0.2			
		V <sub>GS</sub> = -15V, V <sub>DS</sub> = 0V, T <sub>A</sub> = 125°C				-1	μA
V <sub>GS(OFF)</sub>	Gate to Source Cutoff Voltage	V <sub>DS</sub> = 10V, I <sub>D</sub> = 0.5nA	-0.75	-5	-0.75	-5	v
I <sub>DSS</sub>	Drain to Source Saturation Current	$V_{GS} = 0V, V_{DS} = 10V$ (Pulsed)	15	50	15	50	mA

## **Dynamic Characteristics** (@ TA = 25°C, Unless otherwise specified)

			2N6453		2N6	2N6454	
	Parameters	Conditions	Min	Max	Min	Max	Unit
G <sub>FS</sub>	Forward Transconductance	V <sub>DS</sub> = 10V, I <sub>D</sub> = 15mA, f = 1kHz	20	40	20	40	mS
Gos	Output Conductance	V <sub>DS</sub> = 10V, I <sub>D</sub> = 15mA, f = 1kHz		100		100	μS
Ciss	Input Capacitance	V <sub>DS</sub> = 10V, I <sub>D</sub> = 15mA, f = 1MHz		25		25	pF
C <sub>rss</sub>	Reverse Transfer Capacitance	V <sub>DS</sub> = 10V, I <sub>D</sub> = 15mA, f = 1MHz		5		5	pF
en	Equivalent Circuit Input Noise Voltage	V <sub>DS</sub> = 10V, I <sub>D</sub> = 5mA, f = 10Hz V <sub>DS</sub> = 10V, I <sub>D</sub> = 5mA, f = 1kHz		5 3		10 8	nV/√Hz
NF	Noise Figure	$V_{DS}$ = 10V, $I_D$ = 5mA, f = 10Hz R <sub>G</sub> = 10 k $\Omega$		1.5		2.5	dB



Technical

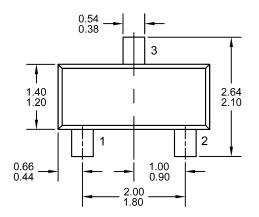
Support

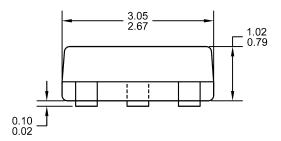
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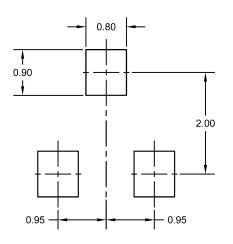
## SOT23 (TO-236AB) Mechanical and Layout Data

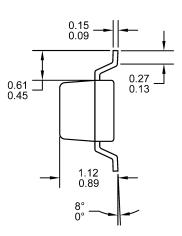
#### **Package Outline Data**





#### Suggested Pad Layout





- 1. All linear dimensions are in millimeters.
- 2. Package weight approximately 0.12 grams
- 3. Molded plastic case UL 94V-0 rated
- For Tape and Reel specifications refer to InterFET CTC-021 Tape and Reel Specification, Document number: IF39002
- 5. Bulk product is shipped in standard ESD shipping material
- 6. Refer to JEDEC standards for additional information.

- 1. All linear dimensions are in millimeters.
- 2. The suggested land pattern dimensions have been provided for reference only. A more robust pattern may be desired for wave soldering.





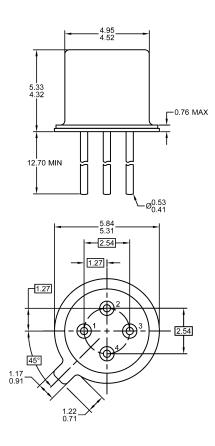
Order

Now

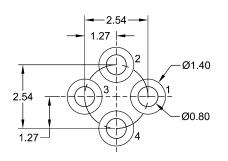
## 2N6453-4

## **TO-72 Mechanical and Layout Data**

#### **Package Outline Data**



#### Suggested Through-Hole Layout



- 1. All linear dimensions are in millimeters.
- 2. Four leaded device. Not all leads are shown in drawing views.
- 3. Package weight approximately 0.31 grams
- 4. Bulk product is shipped in standard ESD shipping material
- 5. Refer to JEDEC standards for additional information.

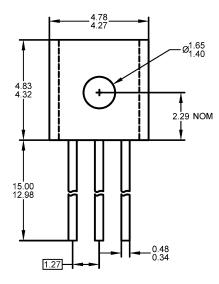
- 1. All linear dimensions are in millimeters.
- 2. The suggested land pattern dimensions have been provided as a straight lead reference only. A more robust pattern may be desired for wave soldering and/or bent lead configurations.

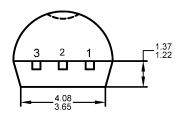




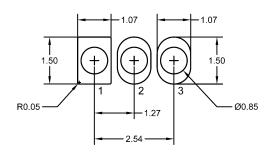
## **TO-92 Mechanical and Layout Data**

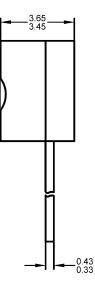
#### **Package Outline Data**





### Suggested Through-Hole Layout





- 1. All linear dimensions are in millimeters.
- 2. Package weight approximately 0.19 grams
- 3. Molded plastic case UL 94V-0 rated
- 4. Bulk product is shipped in standard ESD shipping material
- 5. Refer to JEDEC standards for additional information.

- 1. All linear dimensions are in millimeters.
- 2. The suggested land pattern dimensions have been provided as a straight lead reference only. A more robust pattern may be desired for wave soldering and/or bent lead configurations.

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